

Form 1577-1-48 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. M122-1577		SERIAL NO. 09/730.335	
LIST OF ART CITED BY APPLICANT (Use several sheets if necessary)					
APPLICANT Charles H. Dennison				FILING DATE 12/4/2000	
				GROUP 2811	

U.S. PATENT DOCUMENTS							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
ON	AA	5,668,037	9/97	Prall, et al.			
ON	AB	5,770,496	6/98	Roberts			
ON	AC	5,318,924	6/94	Lin, et al.			
ON	AD	6,479,362B2	11/02	Cunningham			
ON	AE	5,652,464	7/97	Liao, et al.			
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						

FOREIGN PATENT DOCUMENTS							
		Document Number	Date	Country	Class	Subclass	Translation
							Yes No
	AM						
	AN						
	AO						
	AP						

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.)			
ON	AR		Stanley Wolf, "Silicon Processing for the VLSI Era: Vol. 2," Lattice Press, Sunset Beach, CA. (1990) pp.273-276.
ON	AS		J.D. Hayden, F.K. Baker, S.A. Ernst, R.E. Jones, J. Klein, M. Lien, T.F. McNelly, T.C. Mele, H. Mendez, B-Y Nohden, L.C. Parrillo, W. Paulson, J.R. Pfeister, F. Pintchovski, Y-C See, R. Sivan, B.M. Somero, and E.O. Travis, "A High Performance Half
ON	AT		"Micrometer Generation CMOS Technology for Fast SRAM's," IEEE Trans. On Electron Devices, Vol. 38, No. 4 (1991), pp. 876-886.

EXAMINER ON	DATE CONSIDERED 5/6/03
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EV085427256

Form PTO-143		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE			ATTY. DOCKET NO. M122-1577		SERIAL NO. 09/730.335	
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U.S. PATENT DOCUMENTS							
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	AA						
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FOREIGN PATENT DOCUMENTS							
Document Number	Date	Country	Class	Subclass	Translation		
					Yes	No	
AM							
AN							
AO							
AP							
AQ							

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.)			
ON	AR		W-H. Chang, B. Davari, MR. Wordeman, Y. Taur, C. Hsu, and M.D. Rodriguez, "A High Performance 0.25-um CMOS Technology: Design and Characterization," IEEE Trans. On Electron Devices, Vol. 39, No. 4, (1992), pp. 959-966.
	AS		
	AT		

EXAMINER <div style="text-align: center; font-size: 1.5em;">ON</div>	DATE CONSIDERED <div style="text-align: center; font-size: 1.5em;">5/6/03</div>
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